NSN 5961-01-329-9537



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Inclosure Material:
Glass
Overall Length:
Between 0.195 inches and 0.300 inches
Terminal Length:
Between 1.000 inches and 1.500 inches
Overall Diameter:
Between 0.078 inches and 0.107 inches
Function For Which Designed:
Voltage variable capacitor
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-7
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case and quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 working peak reverse voltage, peak total value and 30.0 breakdown voltage, dc
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
27.54
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/436 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

No

Fiig:

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